



PJX8838

50V N-Channel Enhancement Mode MOSFET- ESD Protected

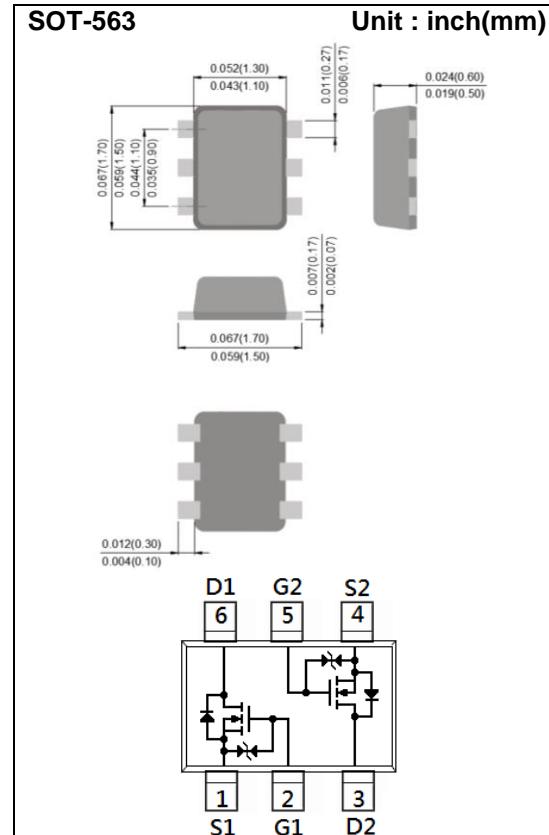
Voltage **50 V** **Current** **360 mA**

Features

- RDS(ON) , VGS@10V, ID@500mA<1.45Ω
- RDS(ON) , VGS@4.5V, ID@200mA<1.95Ω
- RDS(ON) , VGS@2.5V, ID@100mA<4.0Ω
- RDS(ON) , VGS@1.8V, ID@10mA<6.0Ω
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-563 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0026 grams
- Marking : X38



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	50	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	360	mA
Pulsed Drain Current	I_{DM}	1200	mA
Power Dissipation	P_D	300	mW
		2.4	$\text{mW}/^\circ\text{C}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance - Junction to Ambient ^(Note 3)	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	50	-	-	V
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	0.5	0.86	1.0	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=500\text{mA}$	-	1.2	1.45	Ω
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=200\text{mA}$	-	1.3	1.95	
		$\text{V}_{\text{GS}}=2.5\text{V}, \text{I}_D=100\text{mA}$	-	1.7	4.0	
		$\text{V}_{\text{GS}}=1.8\text{V}, \text{I}_D=10\text{mA}$	-	4.0	6.0	
Zero Gate Voltage Drain Current	I_{DSS}	$\text{V}_{\text{DS}}=50\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	± 10	μA
Dynamic ^(Note 4)						
Total Gate Charge	Q_g	$\text{V}_{\text{DS}}=25\text{V}, \text{I}_D=500\text{mA}, \text{V}_{\text{GS}}=4.5\text{V}$	-	0.95	-	nC
Gate-Source Charge	Q_{gs}		-	0.34	-	
Gate-Drain Charge	Q_{gd}		-	0.32	-	
Input Capacitance	C_{iss}	$\text{V}_{\text{DS}}=25\text{V}, \text{V}_{\text{GS}}=0\text{V}, \text{f}=1.0\text{MHZ}$	-	36	-	pF
Output Capacitance	C_{oss}		-	11	-	
Reverse Transfer Capacitance	Crss		-	6.6	-	
Turn-On Delay Time	$\text{t}_{\text{d(on)}}$	$\text{V}_{\text{DD}}=25\text{V}, \text{I}_D=500\text{mA}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_g=6\Omega$ ^(Note 1,2)	-	2.3	-	ns
Turn-On Rise Time	tr		-	20	-	
Turn-Off Delay Time	$\text{t}_{\text{d(off)}}$		-	7	-	
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	500	mA
Diode Forward Voltage	V_{SD}	$\text{I}_s=500\text{mA}, \text{V}_{\text{GS}}=0\text{V}$	-	0.9	1.5	V

NOTES :

1. Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
4. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

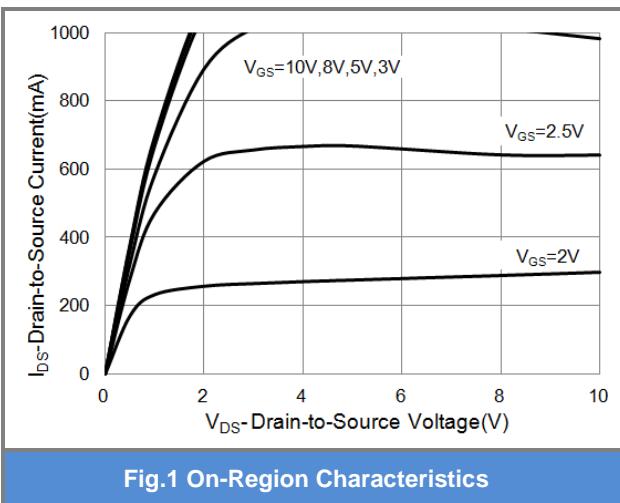


Fig.1 On-Region Characteristics

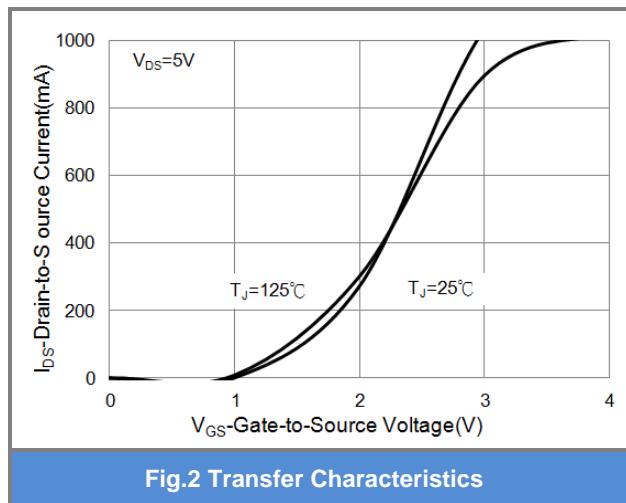


Fig.2 Transfer Characteristics

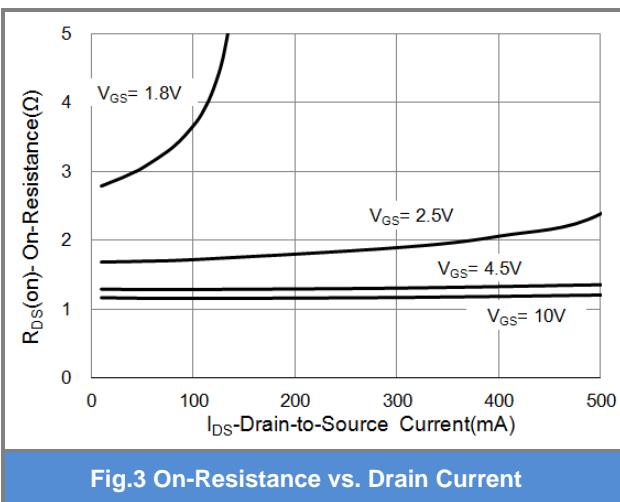


Fig.3 On-Resistance vs. Drain Current

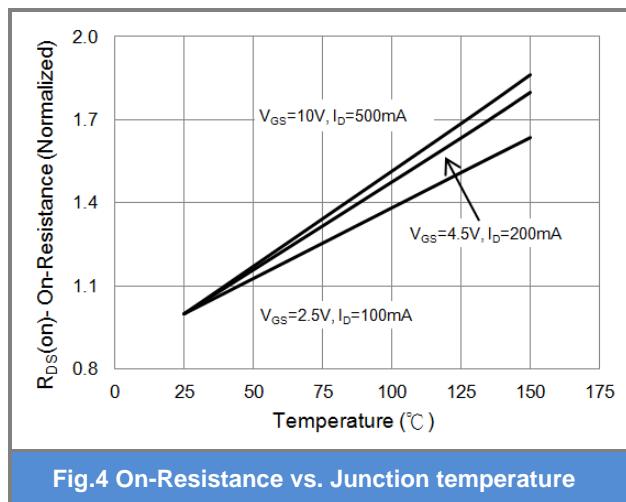


Fig.4 On-Resistance vs. Junction temperature

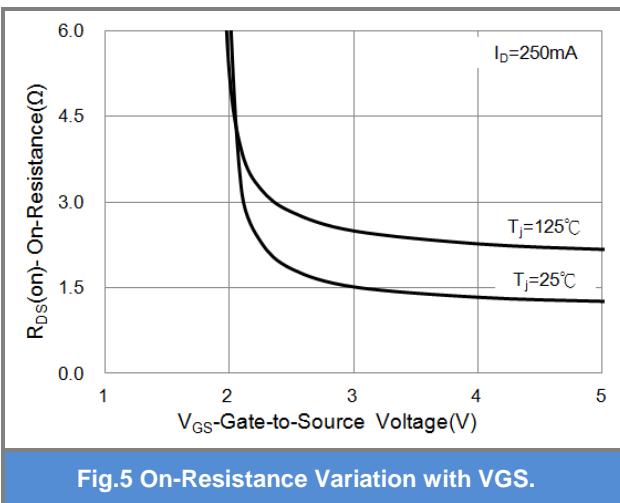


Fig.5 On-Resistance Variation with VGS.

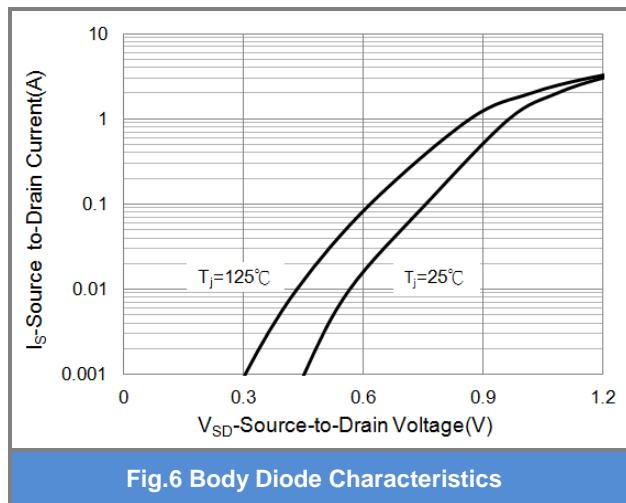


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

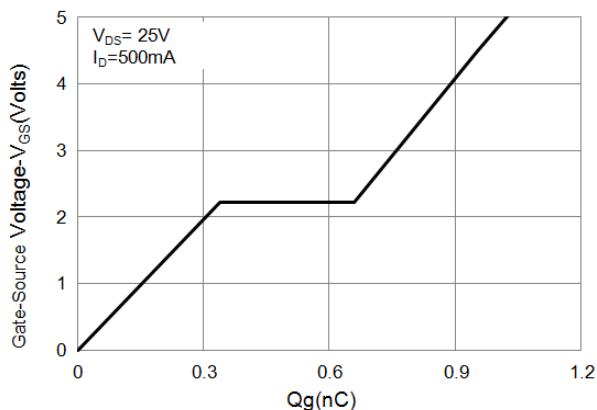


Fig.7 Gate-Charge Characteristics

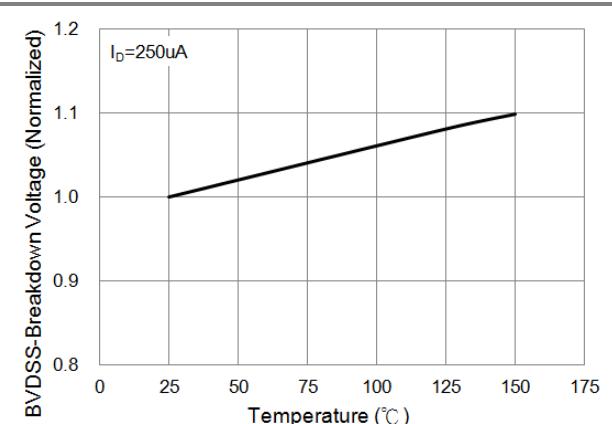


Fig.8 Breakdown Voltage Variation vs. Temperature

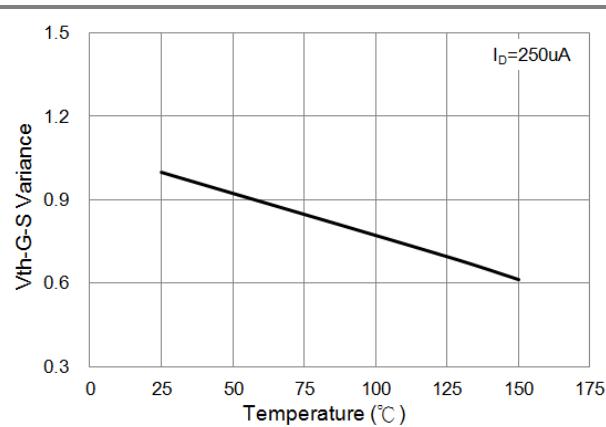


Fig.9 Threshold Voltage Variation with Temperature.

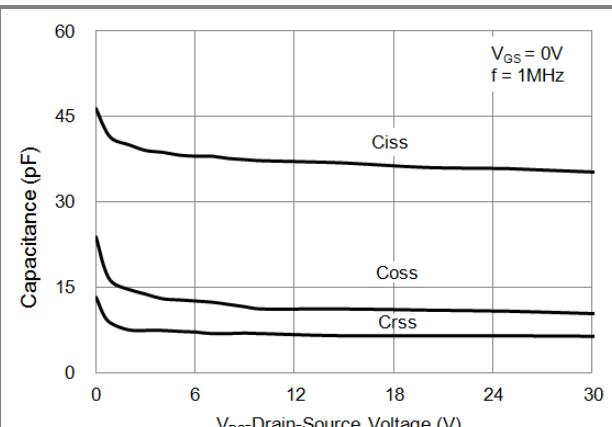


Fig.10 Capacitance vs. Drain-Source Voltage.

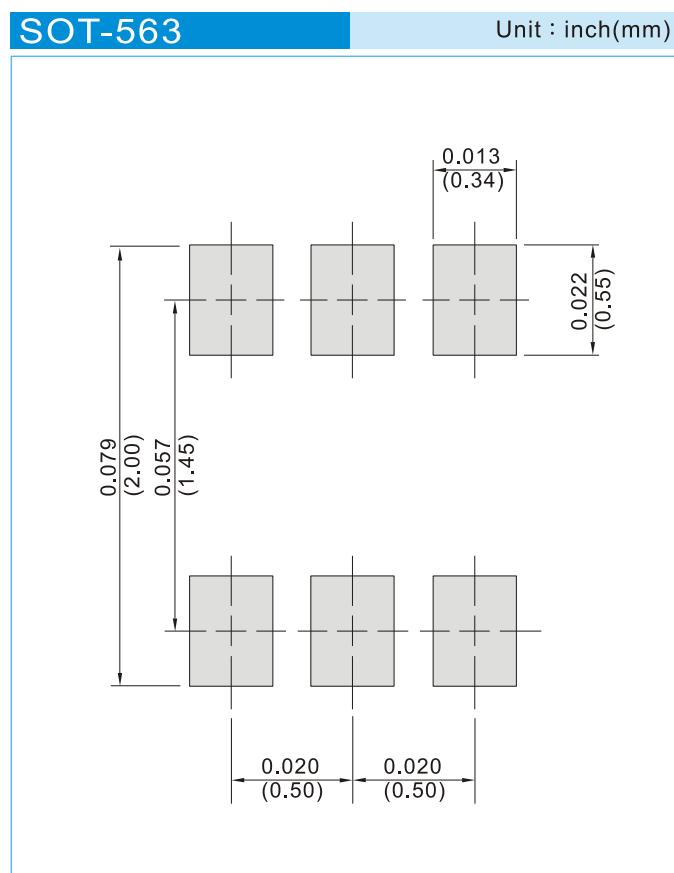


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PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJX8838_R1_00001	SOT-563	4K pcs / 7" reel	X38	Halogen free RoHS compliant
PJX8838_R2_00001	SOT-563	10K pcs / 13" reel	X38	Halogen free RoHS compliant

MOUNTING PAD LAYOUT





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